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IGBT

SGF5N150UF

General Description

Fairchild's Insulated Gate Bipolar Transistor (IGBT) provides low conduction and switching losses. SGF5N150UF is designed for the Switching Power Supply applications.

Features

- High Speed Switching
- Low Saturation Voltage : $V_{CE(sat)} = 4.7 \text{ V} @ I_C = 5A$
- High Input Impedance

Application

Switching Power Supply - High Input Voltage Off-line Converter





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description		SGF5N150UF	Units
V _{CES}	Collector-Emitter Voltage		1500	V
V _{GES}	Gate-Emitter Voltage		± 20	V
Ic	Collector Current	@ T _C = 25°C	10	Α
	Collector Current	@ T _C = 100°C	5	А
I _{CM (1)}	Pulsed Collector Current		20	Α
P_{D}	Maximum Power Dissipation	@ $T_C = 25^{\circ}C$	62.5	W
	Maximum Power Dissipation	@ T _C = 100°C	25	W
T _J	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for Soldering Purposes, 1/8" from Case for 5 Seconds		300	°C

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		2.0	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		40	°C/W

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Chai	racteristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	$V_{GE} = 0V, I_{C} = 1mA$	1500			V
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$			1.0	mA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$			± 100	nA
On Char	acteristics					
V _{GE(th)}	G-E Threshold Voltage	$I_C = 5mA$, $V_{CE} = V_{GE}$	2.0	3.0	4.0	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 5A, V _{GE} = 10V		4.7	5.5	V
Dynamic C _{ies}	Characteristics Input Capacitance	V 40V V 0V		780		pF
	Output Capacitance	$V_{CE} = 10V, V_{GE} = 0V,$		130		рF
C _{oes}	Reverse Transfer Capacitance	f = 1MHz		70		pF
	ng Characteristics					
t _{d(on)}	Turn-On Delay Time	.,		10		ns
t _r	Rise Time	$V_{CC} = 600 \text{ V}$ $I_{C} = 5\text{A}$		15		ns
t _{d(off)}	Turn-Off Delay Time	$I_C = 5A$ $R_G = 10\Omega$		30	50	ns
t _f	Fall Time	$V_{GF} = 10V$		70	120	ns
E _{on}	Turn-On Switching Loss	Inductive Load T _C = 25°C		190		uJ
E _{off}	Turn-Off Switching Loss			100		uJ
E _{ts}	Total Switching Loss	_		290	580	uJ
Q_g	Total Gate Charge	$V_{CF} = 600 \text{ V}, I_{C} = 5\text{A}$		30	45	nC
Q_{ge}^{-}	Gate-Emitter Charge	$V_{CE} = 000 \text{ V}, I_{C} = 3A$ - $V_{GE} = 10V$		3	5	nC
Q_{gc}	Gate-Collector Charge	· GE - 10 *		15	25	nC

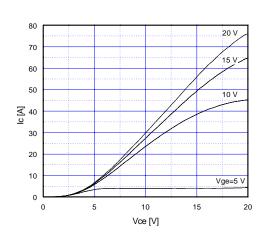


Fig 1. Typical Output Characteristics

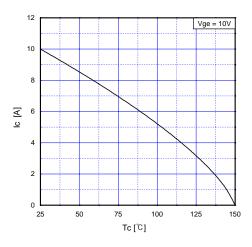


Fig 3. Maximum Collector Current vs. Case Temperature

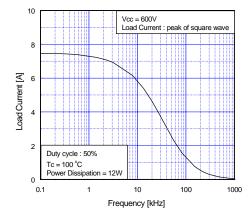


Fig 5. Load Current vs. Frequency

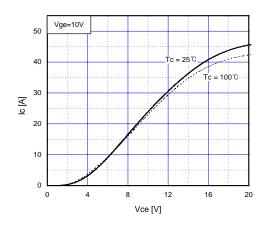


Fig 2. Typical Output Characteristics

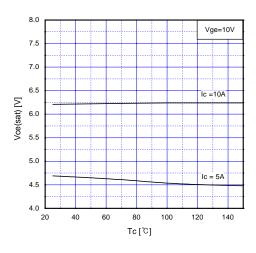


Fig 4. Saturation Voltage vs. Case Temperature

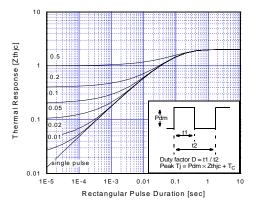


Fig 6. Transient Thermal Impedance of IGBT Junction to Case

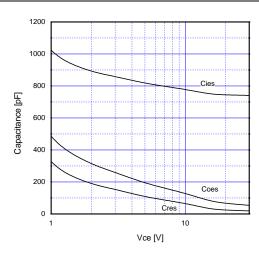


Fig 7. Typical Capacitance vs.
Collector to Emitter Voltage

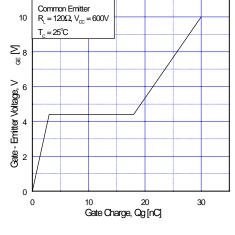


Fig 8. Typical Gate Charge Characteristic

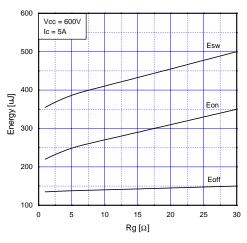


Fig 9. Typical Switching Loss vs.
Gate Resistance

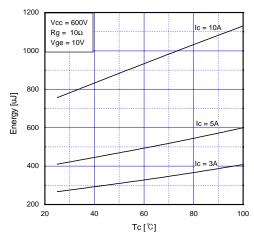


Fig 10. Typical Switching Loss vs. Case Temperature

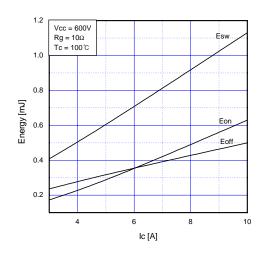


Fig 11. Typical Switching Loss vs. Collector Current

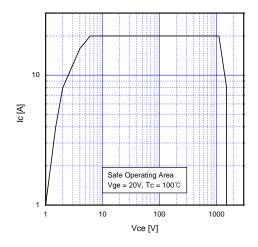
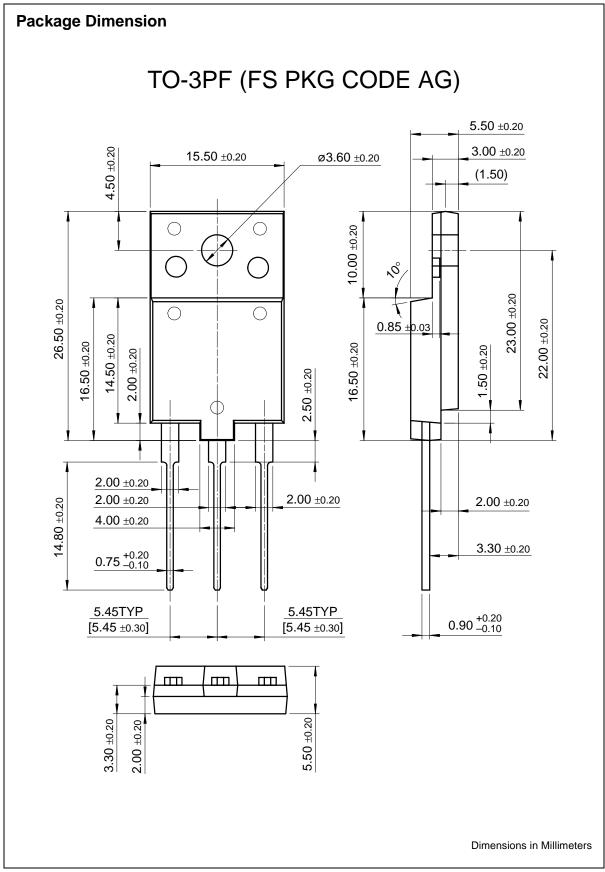


Fig 12. Turn-Off SOA



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